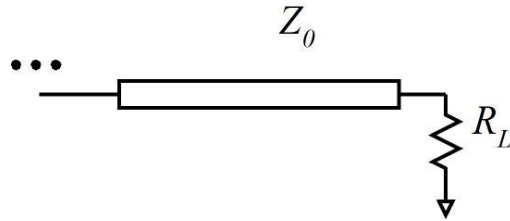


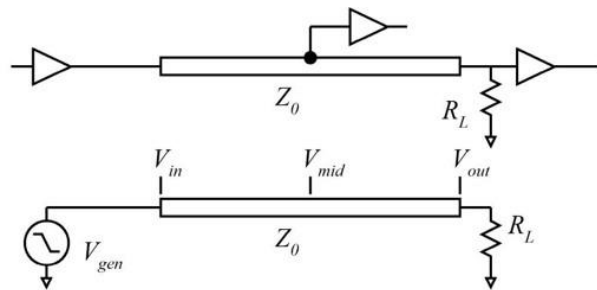
ECE 145a /218A first problem set
(basics of transmission lines and lumped elements)

Problem 1: A transmission line has 50 Ohms characteristic impedance and a load impedance of (a) 25 Ohms (b) 100 Ohms (c) 50 Ohms. Compute in each case the voltage reflection coefficient.



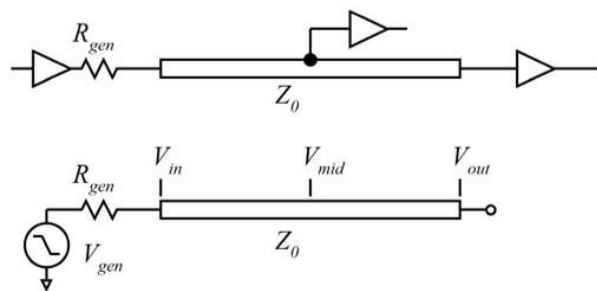
Problem 2: : lattice diagrams:

(a) A logic gate with low (zero ohms) output impedance drives a 50 Ohm transmission line of 1 m length and $2 \cdot 10^8$ m/s propagation velocity. The equivalent circuit is in the lower image. The load impedance is 50 Ohms and V_{gen} is a 1V step-function occurring at time = zero..



Draw clean plots of V_{in} , V_{mid} , and V_{out} as a function of time

(b) a logic gate with 50 Ohms output impedance drives a 50 Ohm transmission line of 1 m length and $2 \cdot 10^8$ m/s propagation velocity. The equivalent circuit is in the lower image. The load impedance is infinity Ohms (an open circuit) and V_{gen} is a 1V step-function occurring at time = zero..



Draw clean plots of V_{in} , V_{mid} , and V_{out} as a function of time

c) Comment of on the relative utility of the 2 schemes for distributing logic signals using a transmission-line bus

Problem 3:

lumped-distributed relationships

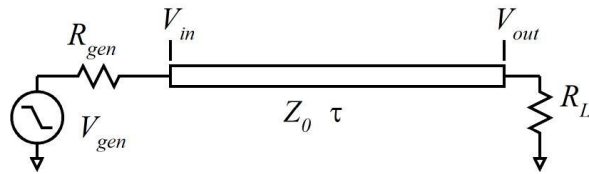
$Z_o = 50 \text{ Ohms}$, $\tau = l/v = 100 \text{ ps}$, and

V_{gen} is a 1 V step-function.

a) $R_L = 250 \text{ } \Omega$, $R_{gen} = 250 \text{ } \Omega$: Compute and plot $V_{in}(t)$ using lattice diagram methods

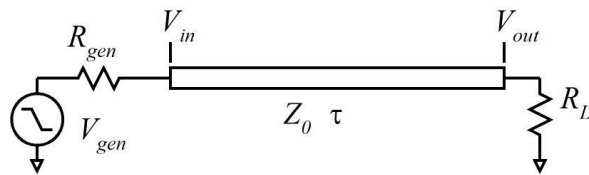
b) $R_L = 10 \text{ } \Omega$, $R_{gen} = 10 \text{ } \Omega$. Compute and plot $V_{in}(t)$ using lattice diagram methods

c) $R_L = 10 \text{ } \Omega$, $R_{gen} = 250 \text{ } \Omega$. Compute and plot $V_{in}(t)$ using lattice diagram methods

**Problem 4:** lumped-distributed relationships

$Z_o = 50 \text{ Ohms}$, $\tau = l/v = 100 \text{ ps}$, and

V_{gen} is a 1 V step-function.



In each of the cases (a,b,c) below, replace the transmission-line with a T or Pi equivalent circuit, compute and compute and plot $V_{in}(t)$ using basic circuit analysis. Hint: it is easiest to use a T equivalent for (a), a Pi equivalent for (b), and a Pi equivalent for (c). To make the analysis simpler, in cases (a) and (b) first compute L/R and RC time constants, and ignore either L or C if the associated time constant is more than 5:1 less than the dominant time constant. In case (c), the Pi equivalent has two capacitors, but one has a much shorter time constant $(C/2)R_L$ than the other $(C/2)R_{gen}$; therefore ignore the capacitor $(C/2)$ connected between the output and ground.

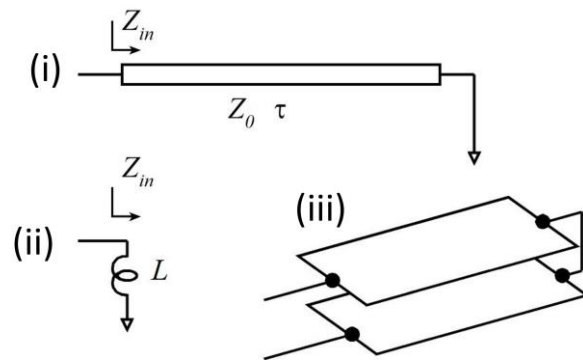
a) $R_L = 250 \text{ } \Omega$, $R_{gen} = 250 \text{ } \Omega$:

b) $R_L = 10 \text{ } \Omega$, $R_{gen} = 10 \text{ } \Omega$.

c) $R_L = 10 \text{ } \Omega$, $R_{gen} = 250 \text{ } \Omega$.

Problem 5: lumped-distributed relationships

A transmission line (iii) has length $l = 10$ cm and propagation velocity and v equal to the speed of light in Teflon (look up its dielectric constant). $Z_o = 50$ Ohms.



a) The plate vertical separation is 1 mm. Using approximate microstrip-line formulas, compute the *width* of the conductor.

b) Using the relationship $L = Z_o \tau = Z_o l / v$, compute (ii) the line inductance. Compute the impedance $Z_{in} = j\omega L$ from DC to a frequency of $f_{high} = v / l$

c) The transmission-line is short-circuited (i). Using the relationships $Z_{load} = 0\Omega$,

$$\Gamma_{load} = \left(\frac{Z_L}{Z_o} - 1 \right) / \left(\frac{Z_L}{Z_o} + 1 \right),$$

$$\Gamma_{in} = \Gamma_L \exp(-j2\beta l) = \Gamma_L \exp(-j2\omega\tau) = \Gamma_L \exp(-j4\pi l / \lambda)$$

$$\text{and } Z_{in} = Z_o \left(\frac{1 + \Gamma_{in}}{1 - \Gamma_{in}} \right)$$

....derive an algebraic expression for Z_{in} .

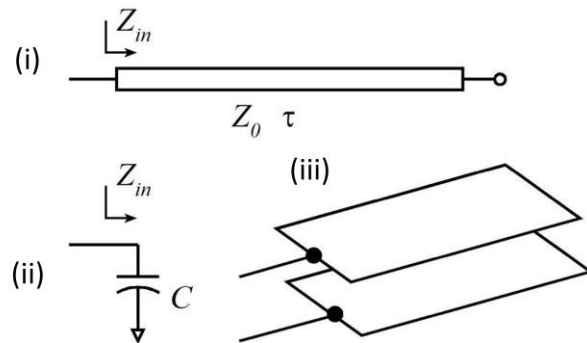
d) Using the Smith chart, compute Z_{in} at the following frequencies:

$$f = 0, v/8l, 2v/8l, 3v/8l, 4v/8l, 5v/8l, 6v/8l, 7v/8l,$$

e) Using *cartesian* axes (straight lines, not a Smith chart), make a plot of the imaginary part of Z_{in} , plotting the answers from parts (b), (c), and (d). Comment on the similarities and differences between the three curves

Problem 6: lumped-distributed relationships

A transmission line (iii) has length $l = 10$ cm and propagation velocity, and v equal to the speed of light in Teflon (look up its dielectric constant). $Z_o = 50$ Ohms.



a) Using the relationship $C = \tau / Z_o = l / vZ_o$, compute (ii) the line capacitance. Compute the impedance $Z_{in} = 1 / j\omega C$ from DC to a frequency of $f_{high} = v / l$

b) The transmission-line is short-circuited (i). Using the relationships $Z_{load} = \infty \Omega$,

$$\Gamma_{load} = \left(\frac{Z_L}{Z_o} - 1 \right) / \left(\frac{Z_L}{Z_o} + 1 \right),$$

$$\Gamma_{in} = \Gamma_L \exp(-j2\beta l) = \Gamma_L \exp(-j2\omega\tau) = \Gamma_L \exp(-j4\pi l / \lambda)$$

and $Z_{in} = Z_o \left(\frac{1 + \Gamma_{in}}{1 - \Gamma_{in}} \right)$

....derive an algebraic expression for Z_{in} .

c) Using the Smith chart, compute Z_{in} at the following frequencies:

$$f = 0, v/8l, 2v/8l, 3v/8l, 4v/8l, 5v/8l, 6v/8l, 7v/8l,$$

e) Using *cartesian* axes (straight lines, not a Smith chart), make a plot of the imaginary part of Z_{in} , plotting the answers from parts (a), (b), and (c). Comment on the similarities and differences between the three curves